.•	TV	#	1	F 1000 0	1	
	J.	# L	3	S arch I Xt	DBs	
_	BRS	F93	416	((angl\$4 or inclin\$4 or theta or phi or slant\$4 or tilt\$4) near4 (inplant or implant or implant or implant or same (Idd or light\$4 near2 dop\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
7	BRS	L64	56	(resist or photoresist or pr) same silylat\$4 same (oxidat\$4 or oxidiz\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
8	BRS	1 65	0	63 and 64	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
4	BRS	997	821	(resist or photoresist or pr) near8 silylat\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
2	BRS	L67	<u>-</u>	63 and 66	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	

	Туре	#7	Hits	Search T xt	DBs
9	BRS	897	8782	hard near2 mask\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	697	0	63 same 64	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
∞	BRS	L70	338423	si?n? or "si.sub.3 or n.sub.4" or nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
O	BRS	L771	26300	psg or bpsg or (silicate near2 glass) near2 (phosphor\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
10	BRS	L72	33	63 same (70 or 71)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Туре	# T	Hits	Search T xt	DBs
<u> </u>	BRS	L73	28	72 and (@ad < "20020908")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
12	BRS	L74	113254 5	taper\$4 or round\$4 or facet\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
73	BRS	L75	· ·	63 same 74	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
14	BRS	P. 7.9	37	63 and 74	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
15	BRS	127	3688	((angl\$4 or inclin\$4 or theta or phi or slant\$4 or tilt\$4) near4 (inplant or implant or implanting or implanting))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

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	Type	# 	Hits	Search T xt	DBs
16	BRS	627	29	(74 same 77).ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
17	BRS	780	32	72 and (@ad < "20030826")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
18	BRS	L81	4	80 not 73	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
19	BRS	L82	28	80 and (@ad < "20020908")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
20	BRS	F.78	221	74 same 77	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

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	Type	# 	Hits	Search Text	DBs
21	BRS	F83	281035 2	semiconductor or silicon or sil	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
22	BRS	F84	40	78 and 83	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
23	BRS	L85	281035 2	semiconductor or silicon or sil	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
24	BRS	987	40	78 and 85	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
25	IS&R	187	840	((438/302) or (438/184) or (438/185) or (438/525)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB